

2-Bit Dual-Supply Level Translator

Product Preview

T30LMXT3V2T244, T30LMXT3V2T240

The T30LMXT3V2T244 / T30LMXT3V2T240 are 2-bit configurable dual-supply level translators with 3-state outputs. The A- and B- ports are designed to track two different power supply rails, V_{CCA} and V_{CCB} respectively. Both supply rails are configurable from 0.9 V to 3.6 V allowing universal voltage level translation between the A to B ports.

The T30LMXT3V2T244 is a 2-bit level translator that allows non-inverting translations from A to B ports. The T30LMXT4T240 is a 2-bit level translator that allows inverting translations from A to B ports.

The output enable pin (\overline{OE}), when High, disables all the output ports by putting them in 3-state. The \overline{OE} pin is designed to track V_{CCA} .

Features

- Wide V_{CCA} and V_{CCB} Operating Range: 0.9 V to 3.6 V
- Balanced Output Drive: ± 24 mA @ 3.0 V
- High-Speed w/ Balanced Propagation Delay: 2.8 ns max at 3.0 to 3.6 V
- Input/Output Pins OVT to 3.6 V
- Non-preferential V_{CC} Sequencing
- Outputs at 3-State until Active V_{CC} is Reached
- Partial Power-Off Protection
- Outputs Switch to 3-State with either V_{CC} at GND
- Typical Max Data Rates:
 - 400 Mbps (≥ 1.8 -V to 3.3-V Translation)
 - 200 Mbps (≥ 1.1 -V to [1.8-V, 2.5-V, 3.3-V] Translation)
 - 150 Mbps (≥ 1.1 -V to 1.5-V Translation)
 - 100 Mbps (≥ 1.1 -V to 1.2-V Translation)
- Small Pb-Free Packaging: SOIC-8, Micro8, UDFN8
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Mobile Phones, PDAs, Other Portable Devices
- Automotive
- Industrial

This document contains information on a product under development. onsemi reserves the right to change or discontinue this product without notice.

MARKING DIAGRAMS



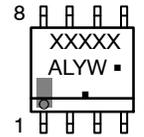
UDFN8
MU SUFFIX
CASE 517AJ



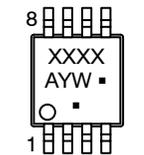
XX = Specific Device Code
M = Date Code
▪ = Pb-Free Package



SO-8
D SUFFIX
CASE 751



Micro8
DM SUFFIX
CASE 846A



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

T30LMXT3V2T244, T30LMXT3V2T240

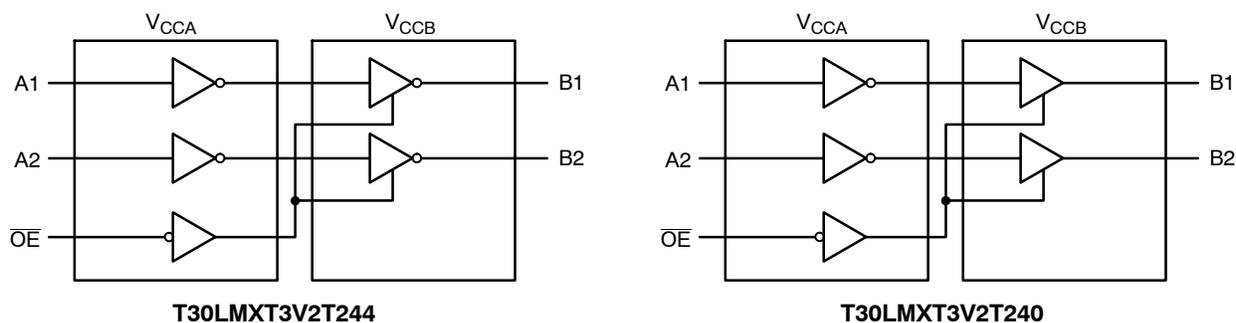


Figure 1. Logic Diagrams

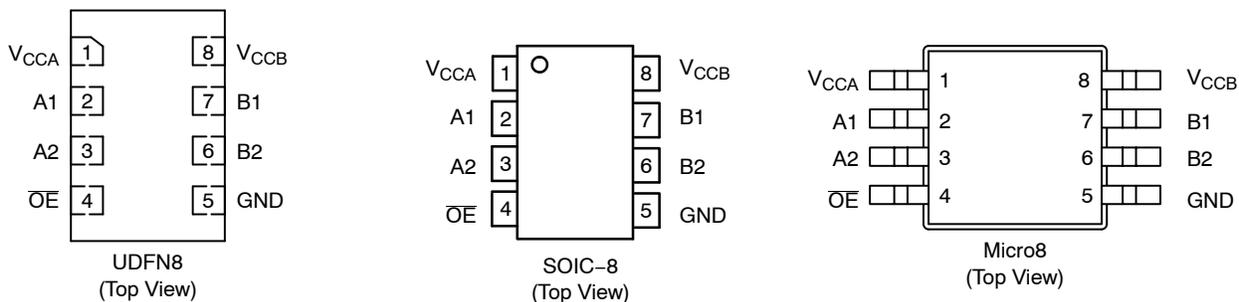


Figure 2. Pin Assignments (Top View)

FUNCTION TABLE

INPUTS		T30LMXT3V2T244 OUTPUT	T30LMXT3V2T240 OUTPUT
\overline{OE}	A_n	B_n	B_n
L	L	L	H
L	H	H	L
H	X	3-State	3-State

PIN NAMES

PINS	DESCRIPTION
V_{CCA}	A Port DC Supply
V_{CCB}	B Port DC Supply
GND	Ground
\overline{OE}	Output Enable
A1, A2	Input Ports
B1, B2	Output Ports

Application Recommendations

During power-up and power-down, it is recommended that the \overline{OE} pin be connected to V_{CC} through pull-up resistors to ensure high impedance at the I/O ports.

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MAXIMUM RATINGS

Symbol	Rating	Value	Condition	Unit	
V_{CCA}, V_{CCB}	DC Supply Voltage	-0.5 to +4.3		V	
V_I	DC Input Voltage	-0.5 to +4.3		V	
V_O	DC Output Voltage (Power Down Mode)	-0.5 to +4.3	$V_{CCA} = V_{CCB} = 0$	V	
	(3-State Mode)	-0.5 to +4.3			
	(Active Mode)	-0.5 to $V_{CCB}+0.5$			
I_{IK}	DC Input Diode Current	-50	$V_I < \text{GND}$	mA	
I_{OK}	DC Output Diode Current	-50	$V_O < \text{GND}$	mA	
I_O	DC Output Source/Sink Current	± 50		mA	
I_{CC}	DC Supply Current Per Supply Pin	± 100		mA	
I_{GND}	DC Ground Current per Ground Pin	± 100		mA	
T_{STG}	Storage Temperature Range	-65 to +150		°C	
θ_{JA}	Thermal Resistance (Note 1)	SOIC-8		134	°C/W
		Micro8		167	
		UDFN8		231	
P_D	Power Dissipation in Still Air	SOIC-8		935	mW
		Micro8		748	
		UDFN8		541	
MSL	Moisture Sensitivity Level		Level 1	-	
F_R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-	
V_{ESD}	ESD Withstand Voltage (Note 2)	Human Body Model	2	kV	
		Charged Device Model	1		
$I_{LATCHUP}$	Latchup Performance (Note 3)		± 100	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 76mm-by-114mm, 2-ounce copper trace no air flow per JESD51-7.
2. HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued per JEDEC/JEP172A.
3. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CCA}, V_{CCB}	Positive DC Supply Voltage	0.9	3.6	V
V_I	Input Voltage	GND	3.6	V
V_O	Output Voltage (Power Down Mode)	GND	3.6	V
	(3-State Mode)	GND	3.6	
	(Active Mode)	GND	V_{CCB}	
T_A	Operating Temperature Range	-40	+125	°C
$\Delta t / \Delta V$	Input Transition Rise or Rate	0	5	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

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DC ELECTRICAL CHARACTERISTICS – INPUT VOLTAGES

Symbol	Parameter	Test Conditions	Port	V _{CCA} (V)	V _{CCB} (V)	T _A = -40°C to +85°C			T _A = -40°C to +125°C		Unit
						Min	Typ (Note 4)	Max	Min	Max	
V _{IH}	Input HIGH Voltage		OE, A	2.7 – 3.6	0.9 – 3.6	2.0	–	–	2.0	–	V
				2.3 – 2.7		1.6	–	–	1.6	–	
				0.9 – 1.95		0.65 V _{CCA}	–	–	0.65 V _{CCA}	–	
V _{IL}	Input LOW Voltage		OE, A	2.7 – 3.6	0.9 – 3.6	–	–	0.8	–	0.8	V
				2.3 – 2.7		–	–	0.7	–	0.7	
				0.9 – 1.95		–	–	0.35 V _{CCA}	–	0.35 V _{CCA}	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. All typical values are at T_A = 25°C.

DC ELECTRICAL CHARACTERISTICS – OUTPUT VOLTAGES

Symbol	Parameter	Test Conditions	V _{CCA} (V)	V _{CCB} (V)	T _A = -40°C to +85°C			T _A = -40°C to +125°C		Unit
					Min	Typ (Note 4)	Max	Min	Max	
V _{OH}	Output HIGH Voltage	V _I = V _{IH} or V _{IL} :								V
		I _{OH} = -100 μA	0.9 – 3.6	0.9 – 3.6	V _{CCB} – 0.1	–	–	V _{CCB} – 0.1	–	
		I _{OH} = -0.5 mA	0.9	0.9	0.7	–	–	0.7	–	
		I _{OH} = -3 mA	1.1	1.1	0.85	–	–	0.85	–	
		I _{OH} = -6 mA	1.4	1.4	1.05	–	–	1.05	–	
		I _{OH} = -8 mA	1.65	1.65	1.2	–	–	1.2	–	
			2.3	2.3	1.8	–	–	1.8	–	
		I _{OH} = -12 mA	2.7	2.7	2.2	–	–	2.2	–	
			2.3	2.3	1.7	–	–	1.7	–	
I _{OH} = -18 mA	3.0	3.0	2.4	–	–	2.4	–			
	3.0	3.0	2.2	–	–	2.2	–			
V _{OL}	Output LOW Voltage	V _I = V _{IH} or V _{IL} :								V
		I _{OL} = 100 μA	0.9 – 3.6	0.9 – 3.6	–	–	0.1	–	0.1	
		I _{OL} = 0.5 mA	0.9	0.9	–	–	0.2	–	0.2	
		I _{OL} = 3 mA	1.1	1.1	–	–	0.25	–	0.25	
		I _{OL} = 6 mA	1.4	1.4	–	–	0.35	–	0.35	
		I _{OL} = 8 mA	1.65	1.65	–	–	0.3	–	0.3	
			2.3	2.3	–	–	0.4	–	0.4	
		I _{OL} = 12 mA	2.7	2.7	–	–	0.4	–	0.4	
			2.3	2.3	–	–	0.4	–	0.4	
I _{OL} = 18 mA	3.0	3.0	–	–	0.4	–	0.4			
	3.0	3.0	–	–	0.55	–	0.55			

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DC ELECTRICAL CHARACTERISTICS – LEAKAGE AND SUPPLY CURRENTS

Symbol	Parameter	Test Conditions	V _{CCA} (V)	V _{CCB} (V)	T _A = -40°C to +85°C		T _A = -40°C to +125°C		Unit	
					Min	Max	Min	Max		
I _I	Input Leakage Current	V _I = 3.6 V or GND	0.9 – 3.6	0.9 – 3.6	–	±0.1	–	±1.0	μA	
I _{OZ}	3-State Output Leakage	$\overline{OE} = V_{IH}$; V _O = GND to 3.6 V	3.6	3.6	–	±0.1	–	±1.0	μA	
I _{OFF}	Power-Off Leakage Current	V _I or V _O = 0 to 3.6 V	A	0	0.9 – 3.6	–	±0.1	–	±1.0	μA
			B	0.9 – 3.6	0	–	±0.1	–	±1.0	
I _{CCA}	Quiescent Supply Current	V _I = V _{CCA} or GND; I _O = 0	0.9 – 3.6	0.9 – 3.6	–	0.5	–	1.0	μA	
			0	0.9 – 3.6	–	-0.1	–	-1		
			0.9 – 3.6	0	–	0.1	–	1.0		
I _{CCB}	Quiescent Supply Current	V _I = V _{CCB} or GND; I _O = 0	0.9 – 3.6	0.9 – 3.6	–	0.5	–	1.0	μA	
			0	0.9 – 3.6	–	0.1	–	1.0		
			0.9 – 3.6	0	–	-0.1	–	-1.0		

NOTE: Connect ground before applying supply voltage V_{CCA} or V_{CCB}. This device is designed with the feature that the power-up sequence of V_{CCA} and V_{CCB} will not damage the IC.

AC ELECTRICAL CHARACTERISTICS (Notes 5 and 6)

Symbol	Parameter	V _{CCA} (V)	T _A = -40°C to +85°C					T _A = -40°C to +125°C					Unit
			V _{CCB} (V)					V _{CCB} (V)					
			3.3	2.5	1.8	1.5	1.2	3.3	2.5	1.8	1.5	1.2	
			Max	Max	Max	Max	Max	Max	Max	Max	Max	Max	
t _{PLH} , t _{PHL}	Propagation Delay, A to B	3.3	2.3	2.8	3.5	4.2	8.0	2.6	3.3	3.9	4.7	8.3	nS
		2.5	2.7	3.1	3.8	4.4	8.2	2.9	3.5	4.2	4.9	8.5	
		1.8	3.2	3.6	4.0	4.6	8.4	3.5	3.9	4.5	5.0	8.7	
		1.5	3.9	4.0	4.4	5.1	8.7	4.1	4.3	4.8	5.5	9.0	
		1.2	4.9	5.0	5.2	6.1	9.0	5.3	5.4	5.9	6.9	9.3	
t _{PZH} , t _{PZL}	Output Enable, OE to B	3.3	3.5	4.2	5.8	8.0	11.3	4.2	4.9	6.7	8.4	11.9	nS
		2.5	4	4.8	6.3	8.3	11.3	4.4	5.3	7.0	8.7	11.9	
		1.8	4.6	5.3	7.0	8.6	11.3	5.1	5.9	7.5	9.0	11.9	
		1.5	5.6	5.8	7.5	8.9	11.3	6.2	6.4	8.0	9.3	11.9	
		1.2	8.7	8.8	9.1	9.8	12.3	8.9	9.0	9.3	10.0	12.5	
t _{PHZ} , t _{PLZ}	Output Disable, OE to B	3.3	5.6	5.6	5.6	5.6	5.6	6.1	6.1	6.1	6.1	6.1	nS
		2.5	6.2	6.2	6.2	6.2	6.2	6.7	6.7	6.7	6.7	6.7	
		1.8	6.9	6.9	6.9	6.9	6.9	7.4	7.4	7.4	7.4	7.4	
		1.5	7.6	7.6	7.6	7.6	7.6	8.2	8.2	8.2	8.2	8.2	
		1.2	9.5	9.5	9.5	9.5	9.5	10.5	10.5	10.5	10.5	10.5	

5. Propagation delays defined per Figure 3.

6. These parameters are guaranteed by characterization and are not production tested.

CAPACITANCE

Symbol	Parameter	Test Conditions	Typ (Note 4)	Unit
C _{IN}	Control Pin Input Capacitance	V _{CCA} = V _{CCB} = 3.3 V, V _I = 0 V or V _{CCA}	2.5	pF
C _{I/O}	I/O Pin Input Capacitance	V _{CCA} = V _{CCB} = 3.3 V, V _I = 0 V or V _{CCA}	5.0	pF
C _{PD} (Note 7)	Power Dissipation Capacitance	V _{CCA} = V _{CCB} = 3.3 V, V _I = 0 V or V _{CCA} , f = 10 MHz	12	pF

7. C_{PD} is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from:
I_{CC(operating)} ≈ C_{PD} × V_{CC} × f_{IN} × N_{SW} where I_{CC} = I_{CCA} + I_{CCB} and N_{SW} = total number of outputs switching.

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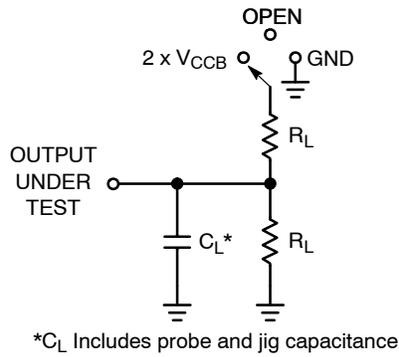


Figure 3. AC Test Circuit

Test	Switch	C _L	R _L
t _{PLH} , t _{PZH}	OPEN	15 pF	2 kΩ
t _{PLZ} , t _{PZL}	2 x V _{CCB}		
t _{PHZ} , t _{PZH}	GND		

C_L includes probe and jig capacitance
Pulse generator Z_O = 50 Ω
Input f = 1.0 MHz; t_W = 500 ns

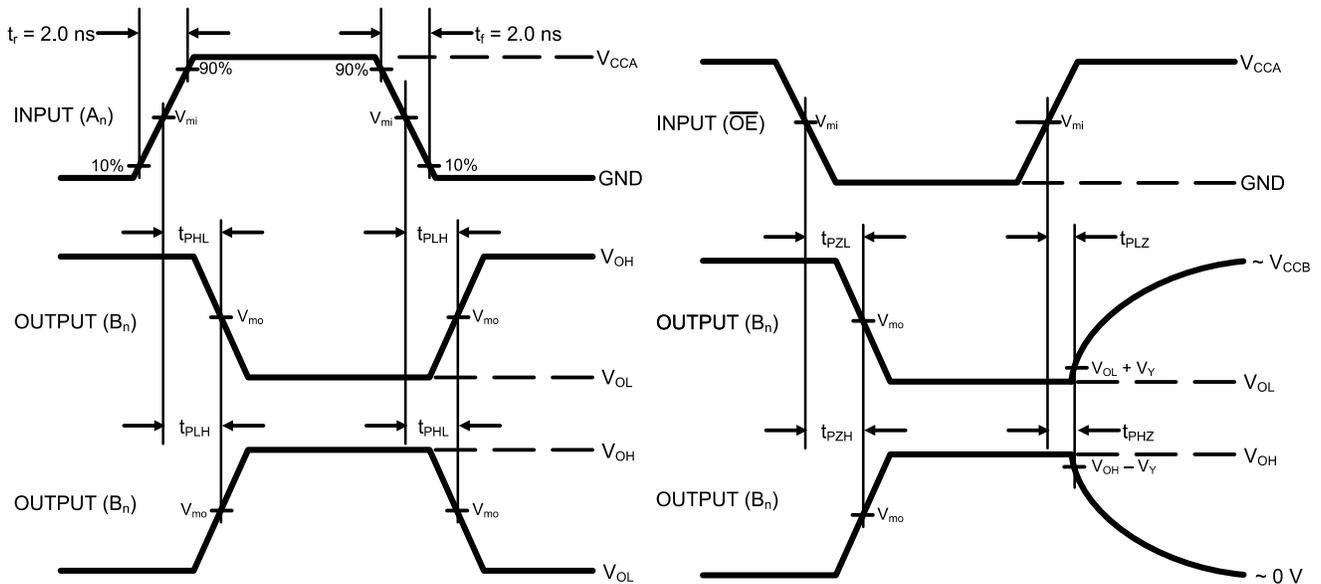


Figure 4. AC Waveforms

Symbol	V _{CC}				
	3.0 V – 3.6 V	2.3 V – 2.7 V	1.65 V – 1.95 V	1.4 V – 1.6 V	1.1 V – 1.3 V
V _{mi}	V _{CCA} /2				
V _{mo}	V _{CCB} /2				
V _Y	0.3 V	0.15 V	0.15 V	0.1 V	0.1 V

T30LMXT3V2T244, T30LMXT3V2T240

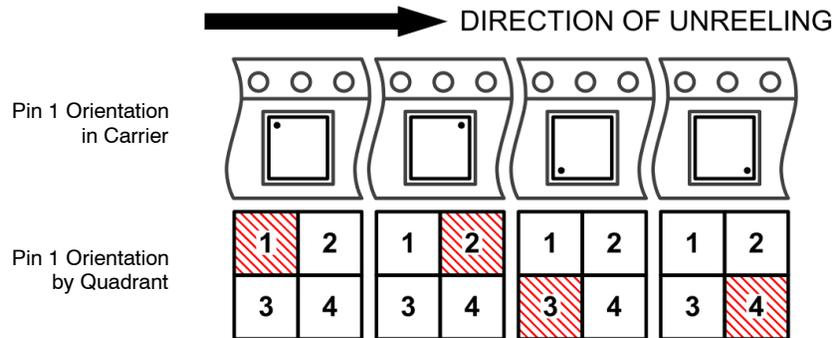
ORDERING INFORMATION

Device	Marking	Package	Pin 1 Quadrant	Shipping [†]
T30LMXT3V2T244MUTAG	TBD	UDFN8	1	3000 Units / Tape & Reel
T30LMXT3V2T244DR2G	TBD	SOIC-8	1	2500 Units / Tape & Reel
T30LMXT3V2T244DMR2G	TBD	Micro8	1	4000 Units / Tape & Reel
T30LAXT3V2T244DMR2G*	TBD	Micro8	1	4000 Units / Tape & Reel
T30LMXT3V2T240MUTAG	TBD	UDFN8	1	3000 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

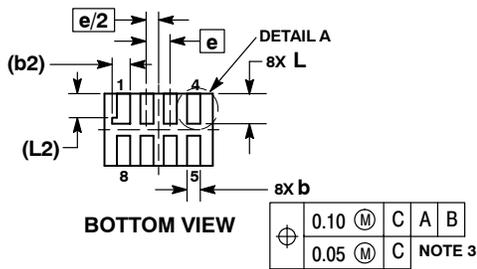
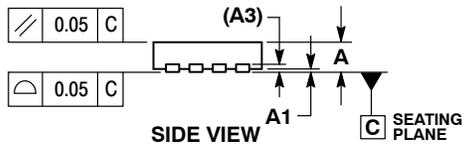
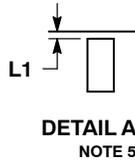
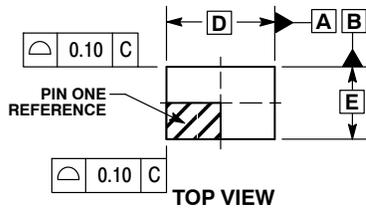
Pin 1 Orientation in Tape and Reel



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PACKAGE DIMENSIONS

UDFN8 1.8 x 1.2, 0.4P
CASE 517AJ
ISSUE O

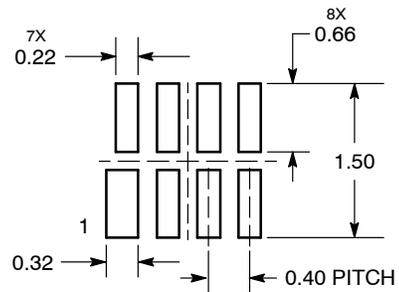


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM TERMINAL TIP.
4. MOLD FLASH ALLOWED ON TERMINALS ALONG EDGE OF PACKAGE. FLASH MAY NOT EXCEED 0.03 ONTO BOTTOM SURFACE OF TERMINALS.
5. DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS.

DIM	MILLIMETERS	
	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A3	0.127	REF
b	0.15	0.25
b2	0.30	REF
D	1.80	BSC
E	1.20	BSC
e	0.40	BSC
L	0.45	0.55
L1	0.00	0.03
L2	0.40	REF

MOUNTING FOOTPRINT SOLDERMASK DEFINED

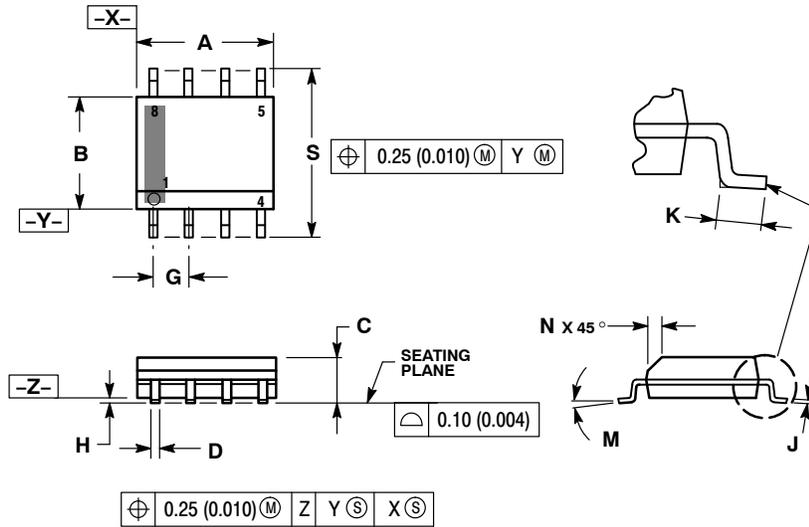


DIMENSIONS: MILLIMETERS

T30LMXT3V2T244, T30LMXT3V2T240

PACKAGE DIMENSIONS

SO-8
CASE 751-07
ISSUE AK

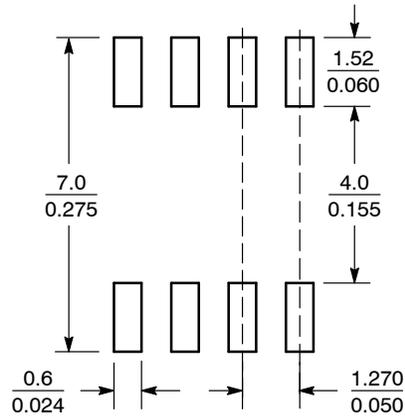


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*



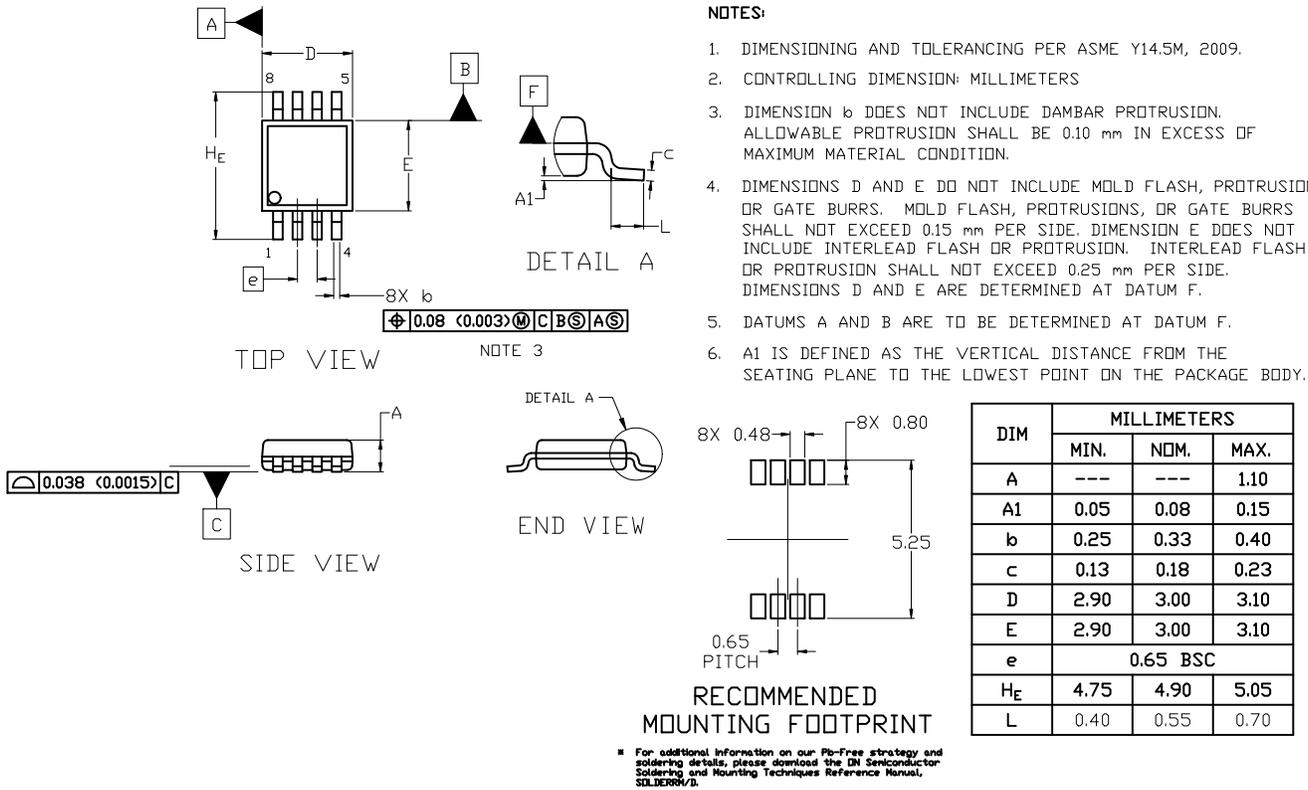
SCALE 6:1 $\left(\frac{\text{mm}}{\text{inches}} \right)$

*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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PACKAGE DIMENSIONS

Micro8 CASE 846A-02 ISSUE K



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